## NSN 5961-00-175-4302

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-175-4302 **Inclosure Material:** Ceramic **Overall Length:** 0.285 inches **Overall Height:** 0.223 inches **Overall Width:** 0.165 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to emitter voltage/static/base open and 120.0 collector to base voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes collector current, dc **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**